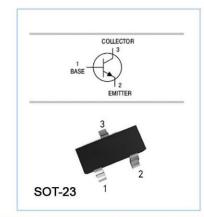


## **NPN Silicon Epitaxial Planar Transistor**

for switching and amplifier applications. Especially suitable for AF-driver stages and low power output stages.

Marking Code: Y1



Absolute Maximum Ratings (T<sub>a</sub> = 25 °C)

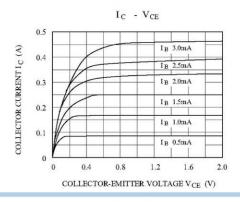
Parameter	Symbol	Value	Unit
Collector Base Voltage	V <sub>CBO</sub>	40	٧
Collector Emitter Voltage	V <sub>CEO</sub>	25	V
Emitter Base Voltage	V <sub>EBO</sub>	6	٧
Collector Current	Ic	1.5	Α
Power Dissipation	P <sub>tot</sub>	350	mW
Junction Temperature	Tj	150	°C
Storage Temperature Range	T <sub>stg</sub>	- 55 to + 150	°C

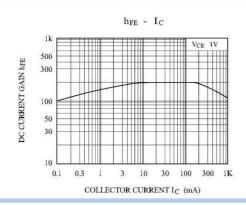
Characteristics at T<sub>a</sub> = 25 °C

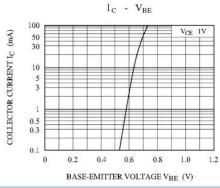
Parameter	Symbol	Min.	Max.	Unit
DC Current Gain at V <sub>CE</sub> = 1 V, I <sub>C</sub> = 100 mA				
at V <sub>CE</sub> = 1 V, I <sub>C</sub> = 800 mA	h <sub>FE</sub>	200	350	-
Collector Base Cutoff Current at V <sub>CB</sub> = 35 V	I <sub>CBO</sub>	-	100	nA
Emitter Base Cutoff Current at V <sub>EB</sub> = 6 V	I <sub>EBO</sub>	-	100	nA
Collector Base Breakdown Voltage at I <sub>C</sub> = 100 µA	V <sub>(BR)CBO</sub>	40	-	V
Collector Emitter Breakdown Voltage at I <sub>C</sub> = 2 mA	V <sub>(BR)CEO</sub>	25	-	V
Emitter Base Breakdown Voltage at $I_E = 100 \mu A$	V <sub>(BR)EBO</sub>	6		٧
Collector Emitter Saturation Voltage at I <sub>C</sub> = 800 mA, I <sub>B</sub> = 80 mA	V <sub>CE(sat)</sub>	=	0.5	V
Base Emitter Saturation Voltage at I <sub>C</sub> = 800 mA, I <sub>B</sub> = 80 mA	$V_{BE(sat)}$	-	1.2	V
Base Emitter Voltage at V <sub>CE</sub> = 1 V, I <sub>C</sub> = 10 mA	V <sub>BE(on)</sub>	-	1	V
Gain Bandwidth Product at $V_{CE}$ = 10 V, $I_{C}$ = 50 mA	f <sub>T</sub>	120	-	MHz

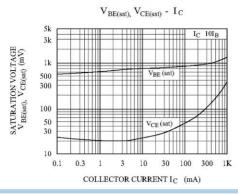


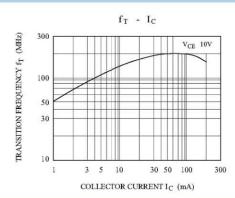


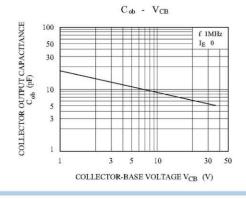


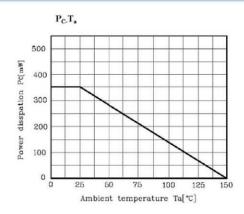








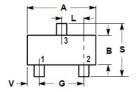








## SOT-23 PACKAGE







## NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M,1982
- 2. CONTROLLING DIMENSION: INCH.

DIM	INCHES		MILLIMETERS		
	MIN	MAX	MIN	MAX	
Α	0.1102	0.1197	2.80	3.04	
В	0.0472	0.0551	1.20	1.40	
C	0.0350	0.0440	0.89	1.11	
D	0.0150	0.0200	0.37	0.50	
G	0.0701	0.0807	1.78	2.04	
Н	0.0005	0.0040	0.013	0.100	
J	0.0034	0.0070	0.085	0.177	
K	0.0140	0.0285	0.35	0.69	
L	0.0350	0.0401	0.89	1.02	
S	0.0830	0.1039	2.10	2.64	
V	0.0177	0.0236	0.45	0.60	